捷多邦,专业PCB打样工厂, SN54HC14 SN74HC14 HEX SCHMITT-TRIGGER INVERTERS

SCLS085B - DECEMBER 1982 - REVISED MAY 1997

 Package Options Include Plastic Small-Outline (D), Thin Shrink
Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

These Schmitt-trigger devices contain six independent inverters. They perform the Boolean function $Y = \overline{A}$ in positive logic.

The SN54HC14 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HC14 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each inverter)

INPUT A	OUTPUT Y
Н	EIL
L	WH.07

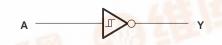
logic symbol[†]

4.6	1	П	2	1Y
1A	3		4	
2A	5		6	2Y
3A	9		8	3Y
4A	11		10	4Y
5A 6A	13		12	5Y 6Y
OA			-c6.4"	01

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, J, N, PW, and W packages.

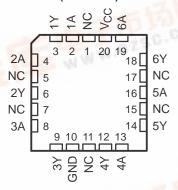
logic diagram (positive logic)



SN54HC14...J OR W PACKAGE SN74HC14...D, N, OR PW PACKAGE (TOP VIEW)

1A [U] V _{CC}
1Y [13] 6A
2A [12] 6Y
2Y [11] 5A
3A [10] 5Y
3Y [9] 4A
GND [7		8] 4Y

SN54HC14 . . . FK PACKAGE (TOP VIEW)



NC – No internal connection

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TEXAS



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absolute maximum ratings over operating free-air temperature range†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (see Note 1)	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC}) (see No	re 1) ±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): D package	e 127°C/W
N packag	e 78°C/W
PW pack	age 170°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

			S	SN54HC14			SN74HC14		
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		2	5	6	2	5	6	V
		V _{CC} = 2 V	1.5			1.5			
VIН	V _{IH} High-level input voltage	$V_{CC} = 4.5 \text{ V}$	3.15			3.15			V
		VCC = 6 V	4.2			4.2			
		V _{CC} = 2 V	0		0.5	0		0.5	
V_{IL}	L Low-level input voltage	$V_{CC} = 4.5 V$	0		1.35	0		1.35	V
		V _{CC} = 6 V	0		1.8	0		1.8	
٧ _I	Input voltage		0		VCC	0		VCC	V
۷o	Output voltage		0		VCC	0		VCC	V
TA	Operating free-air temperature		-55		125	-40		85	°C



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		Vaa	Т	A = 25°C	;	SN54	HC14	SN74HC14		UNIT
PARAMETER			VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
			2 V	1.9	1.998		1.9		1.9		
		I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
Voн	$V_I = V_{IH}$ or V_{IL}		6 V	5.9	5.999		5.9		5.9		V
		$I_{OH} = -4 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		
		$I_{OH} = -5.2 \text{ mA}$	6 V	5.48	5.8		5.2		5.34		
			2 V		0.002	0.1		0.1		0.1	
		I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	
VOL	VI = VIH or VIL		6 V		0.001	0.1		0.1		0.1	V
		I _{OL} = 4 mA	4.5 V		0.17	0.26		0.4		0.33	
		$I_{OL} = 5.2 \text{ mA}$	6 V		0.15	0.26		0.4		0.33	
			2 V	0.7	1.2	1.5	0.7	1.5	0.7	1.5	
V _{T+}			4.5 V	1.55	2.5	3.15	1.55	3.15	1.55	3.15	V
			6 V	2.1	3.3	4.2	2.1	4.2	2.1	4.2	
			2 V	0.3	0.6	1	0.3	1	0.3	1	
V _T			4.5 V	0.9	1.6	2.45	0.9	2.45	0.9	2.45	V
			6 V	1.2	2	3.2	1.2	3.2	1.2	3.2	
			2 V	0.2	0.6	1.2	0.2	1.2	0.2	1.2	
V _{T+} - V _{T-}			4.5 V	0.4	0.9	2.1	0.4	2.1	0.4	2.1	V
			6 V	0.5	1.3	2.5	0.5	2.5	0.5	2.5	
lį	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA
Icc	$V_I = V_{CC}$ or 0,	IO = 0	6 V			2		40		20	μΑ
Ci			2 V to 6 V		3	10		10		10	pF

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Vaa	T,	4 = 25°C	;	SN54H	HC14	SN74H	HC14	UNIT
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		Y	2 V		55	125		190		155	
t _{pd}	A Y		4.5 V		12	25		38		31	ns
			6 V		11	21		32		26	
			2 V		38	75		110		95	
t _t	t _t Y	4.5 V		8	15		22		19	ns	
			6 V		6	13		19		16	

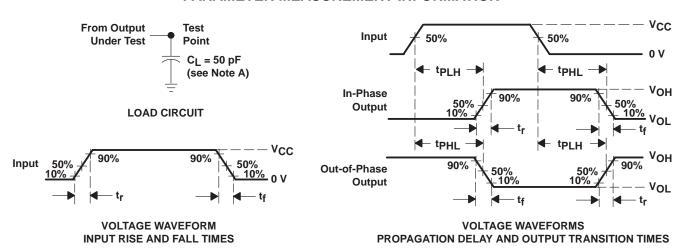
operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
С	d Power dissipation capacitance per inverter	No load	20	pF



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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and test-fixture capacitance.

- B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f = 6 ns, t_f = 6 ns.
- C. The outputs are measured one at a time with one input transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



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